

Thyristor Modules



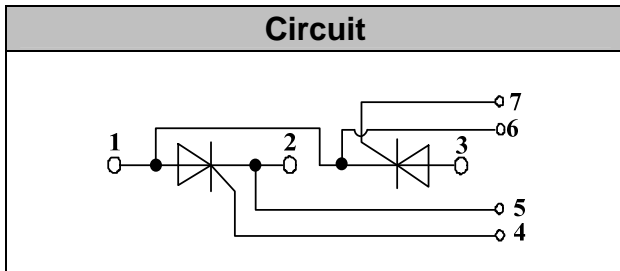
VRRM / VDRM 2200V
ITAV 90A

Applications

- Power Converters
- Lighting Control
- DC Motor Control and Drives
- Heat and temperature control

Features

- International standard package
- High Surge Capability
- Glass passivated chip
- Simple Mounting
- Heat transfer through aluminum oxide DBC ceramic isolated metal baseplate
- UL recognized applied for file no. E360040



Module Type

| TYPE | VRRM | VRSM |
|-----------|-------|-------|
| MT90C22T1 | 2200V | 2300V |

Maximum Ratings

| Symbol | Conditions | Values | Units |
|------------|--|----------------|------------------|
| I_{TAV} | Sine 180°; $T_c=85^\circ\text{C}$ | 90 | A |
| I_{TSM} | $T_{VJ}=45^\circ\text{C}$ t=10ms, sine $T_{VJ}=125^\circ\text{C}$ t=10ms, sine | 2000 1750 | A |
| i^2t | $T_{VJ}=45^\circ\text{C}$ t=10ms, sine $T_{VJ}=125^\circ\text{C}$ t=10ms, sine | 20000 15000 | A ² s |
| V_{isol} | a.c.50HZ;r.m.s.;1min | 3000 | V |
| T_{vj} | | -40 to 130 | °C |
| T_{stg} | | -40 to 125 | °C |
| M_t | To terminals(M5) | $3 \pm 15\%$ | Nm |
| M_s | To heatsink(M6) | $5 \pm 15\%$ | Nm |
| di/dt | $T_{VJ}= T_{VJM}$, $2/3V_{DRM}$, $I_G=500\text{mA}$ $Tr<0.5\mu\text{s}$, $tp>6\mu\text{s}$ | 150 | A/ μs |
| dv/dt | $T_J= T_{VJM}$, $2/3V_{DRM}$, linear voltage rise | 1000 | V/ μs |
| a | Maximum allowable acceleration | 50 | m/s ² |
| Weight | Module(Approximately) | 100 | g |

Thermal Characteristics

| Symbol | Conditions | Values | Units |
|---------------|----------------------------------|-----------|-------|
| $R_{th(j-c)}$ | Cont.;per thyristor / per module | 0.28/0.14 | °C/W |
| $R_{th(c-s)}$ | per thyristor / per module | 0.2/0.1 | °C/W |



Electrical Characteristics

| Symbol | Conditions | Values | | | Units |
|-------------------|---|--------|------|------|---------------|
| | | Min. | Typ. | Max. | |
| V_{TM} | $T=25^{\circ}\text{C}$ $I_{TM}=300\text{A}$ | | | 1.65 | V |
| I_{RRM}/I_{DRM} | $T_{VJ}=T_{VJM}$, $V_R=V_{RRM}$, $V_D=V_{DRM}$ | | | 20 | mA |
| V_{TO} | For power-loss calculations only ($T_{VJ}=125^{\circ}\text{C}$) | | | 0.9 | V |
| r_T | $T_{VJ}=T_{VJM}$ | | | 2 | m Ω |
| V_{GT} | $T_{VJ}=25^{\circ}\text{C}$, $V_D=6\text{V}$ | | | 3 | V |
| I_{GT} | $T_{VJ}=25^{\circ}\text{C}$, $V_D=6\text{V}$ | | | 150 | mA |
| V_{GD} | $T_{VJ}=125^{\circ}\text{C}$, $V_D=2/3V_{DRM}$ | | | 0.25 | V |
| I_{GD} | $T_{VJ}=125^{\circ}\text{C}$, $V_D=2/3V_{DRM}$ | | | 6 | mA |
| I_L | $T_{VJ}=25^{\circ}\text{C}$, $R_G=33\ \Omega$ | | 300 | 600 | mA |
| I_H | $T_{VJ}=25^{\circ}\text{C}$, $V_D=6\text{V}$ | | 150 | 250 | mA |
| tg d | $T_{VJ}=25^{\circ}\text{C}$, $I_G=1\text{A}$, $di_G/dt=1\text{A}/\mu\text{s}$ | | 1 | | μs |
| tq | $T_{VJ}=T_{VJM}$ | | 100 | | μs |



Performance Curves

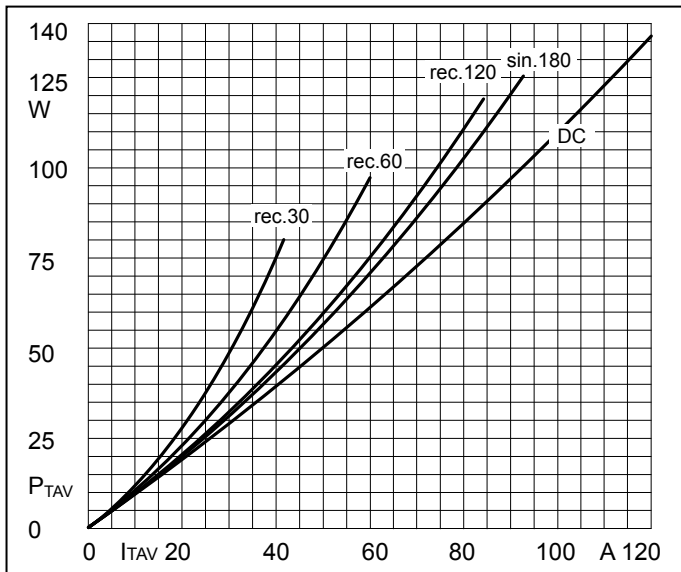


Fig1. Power dissipation

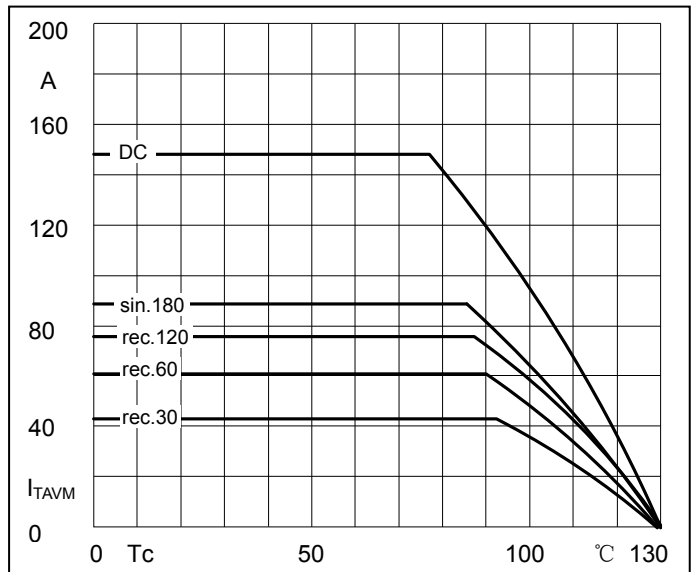


Fig2. Forward Current Derating Curve

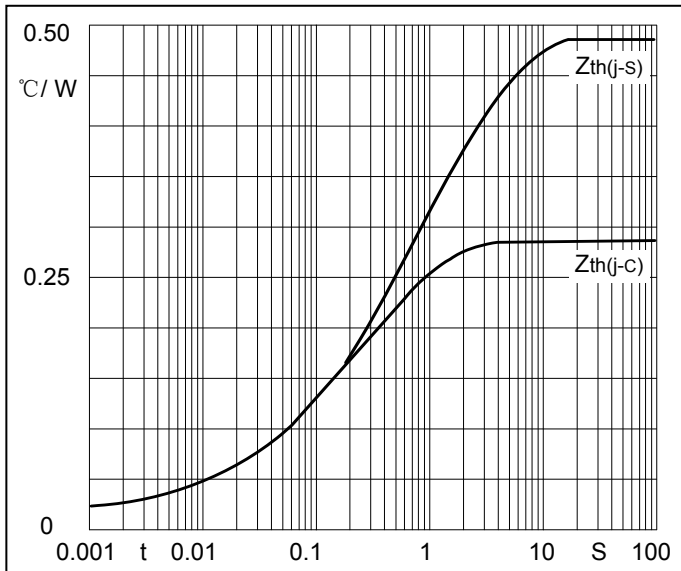


Fig3. Transient thermal impedance

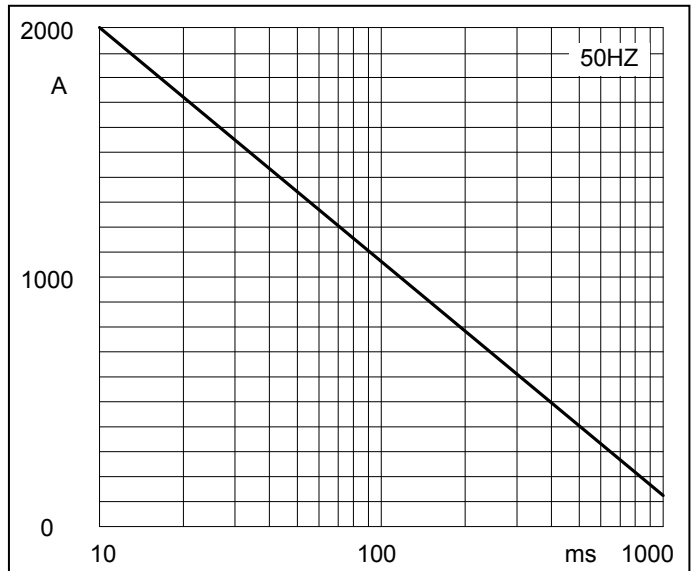


Fig4. Max Non-Repetitive Forward Surge Current

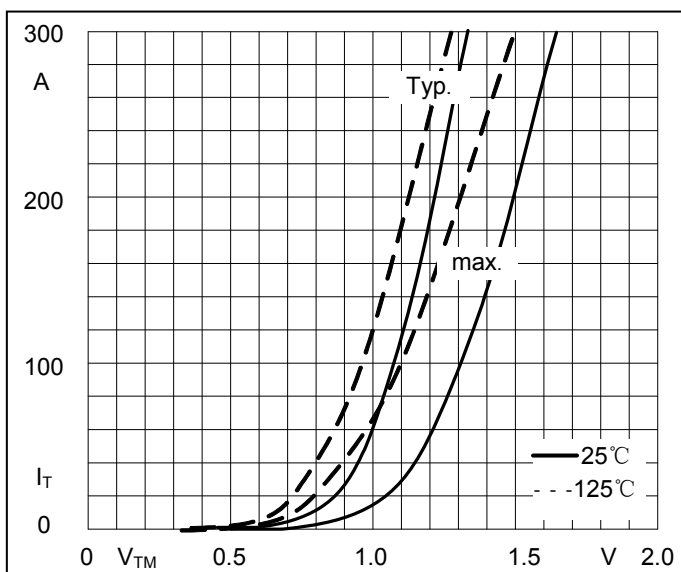


Fig5. Forward Characteristics

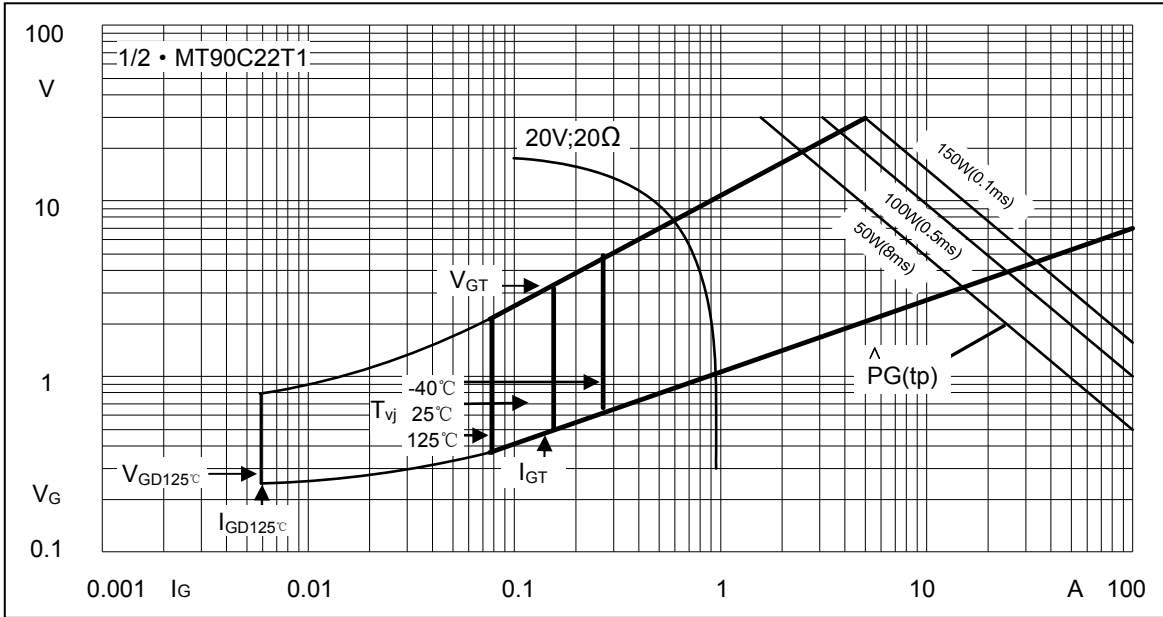
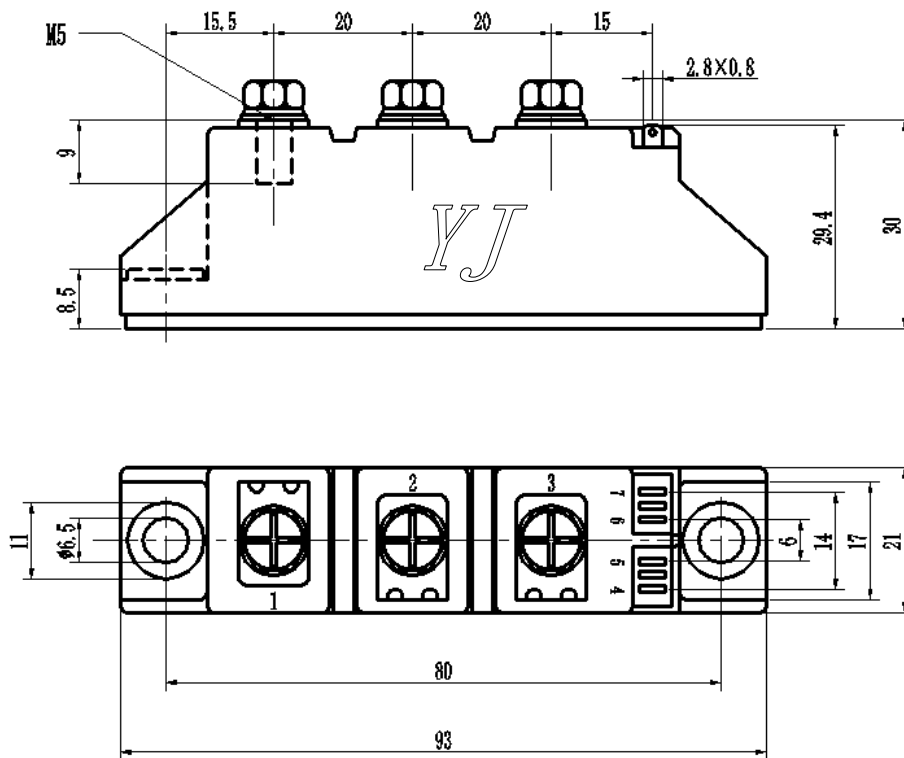


Fig6. Gate trigger Characteristics

Package Outline Information

CASE: T1



Dimensions in mm